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Letters

Correction to "Comments on 'The Dynamical Behavior of a Single-Mode Optical Fiber Strain Gage'"

PATRICIO A. A. LAURA AND JOSE L. POMBO

In the first paragraph of Section II of the above paper,[1] the words "Lagrange—Sophie Germaine's" do not belong there.

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Corrections to "New Narrow-Band Dual-Mode Bandstop Waveguide Filters"

JING-REN QIAN AND WEI-CHEN ZHUANG

In the above paper,[1] equations (1), (3), (4), and (10) were incorrectly printed due to typographical errors. Following are those equations in their correct form.

$$\begin{bmatrix} e_1 \\ 0 \\ 0 \\ \vdots \\ 0 \\ 0 \end{bmatrix} = \begin{bmatrix} Z+R & jM_{12} & jM_{13} & \cdots & & jM_{1n} \\ jM_{12} & Z & jM_{23} & \cdots & & jM_{2n} \\ jM_{13} & jM_{23} & Z & \cdots & & jM_{3n} \\ & & & \cdots & & \vdots \\ \vdots & \vdots & \vdots & \cdots & Z & jM_{n-1n} \\ jM_{1n} & jM_{2n} & jM_{3n} & \cdots & jM_{n-1n} & Z+R_n \end{bmatrix} \begin{bmatrix} i_1 \\ i_2 \\ i_3 \\ \vdots \\ i_{n-1} \\ i_n \end{bmatrix} \tag{1}$$

$$\begin{bmatrix} e_0 \\ 0 \\ 0 \\ \vdots \\ 0 \\ 0 \end{bmatrix} = \begin{bmatrix} R_0 & jM'_{01} & 0 & 0 & \cdots & 0 & R_0 \\ jM'_{01} & Z & jM_{12} & jM_{13} & \cdots & jM_{1n} - \dfrac{jM'_{01}}{2m} & 0 \\ 0 & jM_{12} & Z & jM_{23} & \cdots & jM_{2n} & 0 \\ \cdots & \cdots & \cdots & \cdots & \cdots & \cdots & \cdots \\ 0 & jM_{1n} - \dfrac{jM'_{01}}{2m} & jM_{2n} & jM_{3n} & \cdots & Z & -\dfrac{R_0}{m} \\ m & 0 & 0 & 0 & \cdots & -1 & -m \end{bmatrix} \begin{bmatrix} i'_0 \\ i'_1 \\ i'_2 \\ \vdots \\ i'_n \\ i'_{n+1} \end{bmatrix} \tag{3}$$

$$e'_1 = (Z+R')i'_1 + jM_{12}i'_2 + jM_{13}i'_3 + \cdots + jM_{1n}i'_n$$

$$e'_n = jM_{1n}i'_1 + jM_{2n}i'_2 + \cdots + (Z+R'_n)i'_n \tag{4}$$

$$t' = 1 - \frac{1}{\Delta'}\left(\frac{M'^2_{01}}{2R_0}\Delta'_{11} + \frac{M'^2_{nn+1}}{2R_0}\Delta'_{nn}\right)$$

$$r' = \frac{1}{2R_0\Delta'}\left[M'^2_{01}\Delta'_{11} - M'^2_{nn+1}\Delta'_{nn} + j(-1)^{n+1}2M'_{01}M'_{nn+1}\Delta'_{1n}\right] \tag{10}$$

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[1]J-R. Qian and W-C. Zhuang, *IEEE Trans. Microwave Theory Tech.*, vol. MTT-31, pp. 1045–1050, Dec. 1983.